

# 74AUP2G00

Low-power dual 2-input NAND gate

Rev. 01 — 25 August 2006

Product data sheet

## 1. General description

The 74AUP2G00 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP2G00 provides the dual 2-input NAND function.

## 2. Features

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114-D Class 3A exceeds 4000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101-C exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

**PHILIPS**

### 3. Ordering information

**Table 1. Ordering information**

| Type number | Package | Temperature range | Name   | Description   | Version  |
|-------------|---------|-------------------|--------|---|----------|
| 74AUP2G00DC |         | –40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                  | SOT765-1 |
| 74AUP2G00GT |         | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 |
| 74AUP2G00GM |         | –40 °C to +125 °C | XQFN8  | plastic extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm    | SOT902-1 |

### 4. Marking

**Table 2. Marking**

| Type number | Marking code |
|-------------|--------------|
| 74AUP2G00DC | p00          |
| 74AUP2G00GT | p00          |
| 74AUP2G00GM | p00          |

### 5. Functional diagram

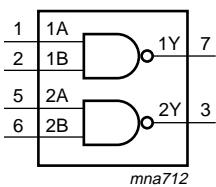


Fig 1. Logic symbol

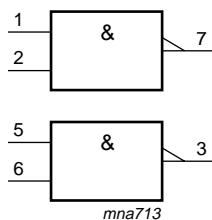


Fig 2. IEC logic symbol

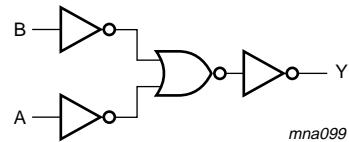


Fig 3. Logic diagram (one gate)

### 6. Pinning information

#### 6.1 Pinning

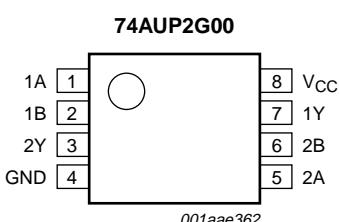
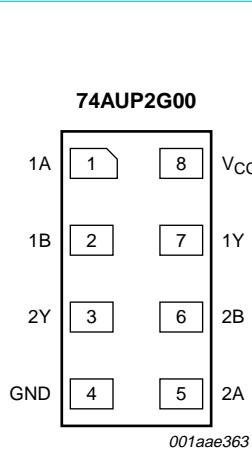
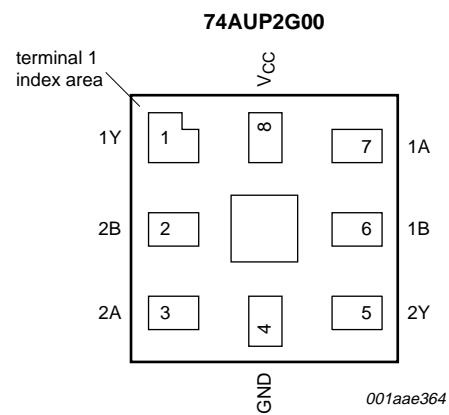


Fig 4. Pin configuration SOT765-1 (VSSOP8)



Transparent top view

Fig 5. Pin configuration SOT833-1 (XSON8)



Transparent top view

Fig 6. Pin configuration SOT902-1 (XQFN8)

## 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin                   |          | Description    |
|-----------------|-----------------------|----------|----------------|
|                 | SOT765-1 and SOT833-1 | SOT902-1 |                |
| 1A              | 1                     | 7        | data input 1A  |
| 1B              | 2                     | 6        | data input 1B  |
| 2Y              | 3                     | 5        | data output 2Y |
| GND             | 4                     | 4        | ground (0 V)   |
| 2A              | 5                     | 3        | data input 2A  |
| 2B              | 6                     | 2        | data input 2B  |
| 1Y              | 7                     | 1        | data output 1Y |
| V <sub>CC</sub> | 8                     | 8        | supply voltage |

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | L  | H      |
| L     | H  | H      |
| H     | L  | H      |
| H     | H  | L      |

[1] H = HIGH voltage level;  
L = LOW voltage level.

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                              | Min      | Max  | Unit |
|------------------|-------------------------|---|----------|------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5     | +4.6 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                    | -        | -50  | mA   |
| V <sub>I</sub>   | input voltage           |   | [1] -0.5 | +4.6 | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V                    | -        | -50  | mA   |
| V <sub>O</sub>   | output voltage          | Active mode and Power-down mode         | [1] -0.5 | +4.6 | V    |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = 0 V to V <sub>CC</sub> | -        | ±20  | mA   |
| I <sub>CC</sub>  | supply current          |   | -        | +50  | mA   |
| I <sub>GND</sub> | ground current          |   | -        | -50  | mA   |
| T <sub>STG</sub> | storage temperature     |   | -65      | +150 | °C   |
| P <sub>TOT</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C    | [2] -    | 250  | mW   |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of P<sub>TOT</sub> derates linearly with 8.0 mW/K.

For XSON8 and XQFN8 packages: above 45 °C the value of P<sub>TOT</sub> derates linearly with 2.4 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

| Symbol           | Parameter                           | Conditions                             | Min | Max             | Unit |
|------------------|-------------------------------------|--|-----|-----------------|------|
| V <sub>CC</sub>  | supply voltage                      |  | 0.8 | 3.6             | V    |
| V <sub>I</sub>   | input voltage                       |  | 0   | 3.6             | V    |
| V <sub>O</sub>   | output voltage                      | Active mode                            | 0   | V <sub>CC</sub> | V    |
|                  |                                     | Power-down mode; V <sub>CC</sub> = 0 V | 0   | 3.6             | V    |
| T <sub>AMB</sub> | ambient temperature                 |  | -40 | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 0.8 V to 3.6 V       | 0   | 200             | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                         | Parameter                            | Conditions  | Min                    | Typ | Max                    | Unit |
|--------------------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b> |                                      |   |                        |     |                        |      |
| V <sub>IH</sub>                | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V   | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | 0.65 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | 1.6                    | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V   | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | -                      | -   | 0.35 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | -                      | -   | 0.7                    | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V   | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V   | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V   | 1.11                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V  | 1.32                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V   | 2.05                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V   | 1.9                    | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V   | 2.72                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V   | 2.6                    | -   | -                      | V    |
| V <sub>OL</sub>                | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V  | -                      | -   | 0.1                    | V    |
|                                |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V  | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V  | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V   | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.44                   | V    |
|                                |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V  | -                      | -   | 0.31                   | V    |
| I <sub>I</sub>                 | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.1                   | µA   |
|                                | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.2                   | µA   |
| ΔI <sub>OFF</sub>              | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.2                   | µA   |
| I <sub>CC</sub>                | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.5                    | µA   |
| ΔI <sub>CC</sub>               | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | [1]                    | -   | 40                     | µA   |
| C <sub>I</sub>                 | input capacitance                    | V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>                             | -                      | 0.8 | -                      | pF   |
| C <sub>O</sub>                 | output capacitance                   | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V   | -                      | 1.7 | -                      | pF   |

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                    | Parameter                            | Conditions  | Min                    | Typ | Max                    | Unit |
|---|--------------------------------------|---|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                                      |   |                        |     |                        |      |
| V <sub>IH</sub>                           | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V   | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|   |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | 0.65 × V <sub>CC</sub> | -   | -                      | V    |
|   |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | 1.6                    | -   | -                      | V    |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                           | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V   | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|   |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | -                      | -   | 0.35 × V <sub>CC</sub> | V    |
|   |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | -                      | -   | 0.7                    | V    |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|   |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V   | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V   | 0.7 × V <sub>CC</sub>  | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V   | 1.03                   | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V  | 1.30                   | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V   | 1.97                   | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V   | 1.85                   | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V   | 2.67                   | -   | -                      | V    |
|   |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V   | 2.55                   | -   | -                      | V    |
| V <sub>OL</sub>                           | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|   |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V  | -                      | -   | 0.1                    | V    |
|   |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V  | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|   |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V  | -                      | -   | 0.37                   | V    |
|   |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V   | -                      | -   | 0.35                   | V    |
|   |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.33                   | V    |
|   |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.45                   | V    |
|   |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V  | -                      | -   | 0.33                   | V    |
|   |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V  | -                      | -   | 0.45                   | V    |
| I <sub>I</sub>                            | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.5                   | µA   |
| I <sub>OFF</sub>                          | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.5                   | µA   |
| ΔI <sub>OFF</sub>                         | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.6                   | µA   |
| I <sub>CC</sub>                           | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 0.9                    | µA   |
| ΔI <sub>CC</sub>                          | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | [1]                    | -   | 50                     | µA   |

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                            | Conditions  | Min                    | Typ | Max                    | Unit |
|--|--------------------------------------|---|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |   |                        |     |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V   | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | 1.6                    | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V   | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
|  |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|  |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | -                      | -   | 0.7                    | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|  |                                      | I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V   | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V   | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V   | 0.93                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V  | 1.17                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V   | 1.77                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V   | 1.67                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V   | 2.40                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V   | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>   |                        |     |                        |      |
|  |                                      | I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 0.8 V to 3.6 V  | -                      | -   | 0.11                   | V    |
|  |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V  | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|  |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V  | -                      | -   | 0.41                   | V    |
|  |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V   | -                      | -   | 0.39                   | V    |
|  |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.36                   | V    |
|  |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V  | -                      | -   | 0.50                   | V    |
|  |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V  | -                      | -   | 0.36                   | V    |
|  |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V  | -                      | -   | 0.50                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                      | -   | ±0.75                  | µA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                      | -   | ±0.75                  | µA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.75                  | µA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 1.4                    | µA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 3.3 V          | [1]                    | -   | 75                     | µA   |

[1] One input at V<sub>CC</sub> - 0.6 V, other input at V<sub>CC</sub> or GND.

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

| Symbol                       | Parameter         | Conditions                                 | 25 °C |                    |      | −40 °C to +125 °C |             |              | Unit |
|------------------------------|-------------------|--|-------|--------------------|------|-------------------|-------------|--------------|------|
|                              |                   |  | Min   | Typ <sup>[1]</sup> | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| <b>C<sub>L</sub> = 5 pF</b>  |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | nA, nB to nY; see <a href="#">Figure 7</a> | [2]   |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                    | -     | 17.5               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V           | 2.5   | 5.3                | 11.0 | 2.1               | 12.2        | 13.5         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V           | 2.0   | 3.8                | 6.8  | 1.8               | 7.8         | 8.6          | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V         | 1.6   | 3.1                | 5.3  | 1.4               | 6.2         | 6.9          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V           | 1.3   | 2.5                | 4.0  | 1.1               | 4.7         | 5.2          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V           | 1.0   | 2.2                | 3.6  | 1.0               | 4.2         | 4.7          | ns   |
| <b>C<sub>L</sub> = 10 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | nA, nB to nY; see <a href="#">Figure 7</a> | [2]   |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                    | -     | 21.0               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V           | 2.4   | 6.1                | 13.0 | 2.2               | 14.4        | 15.9         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V           | 2.4   | 4.4                | 7.9  | 2.2               | 9.2         | 10.2         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V         | 2.0   | 3.7                | 6.2  | 1.9               | 7.3         | 8.1          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V           | 1.4   | 3.0                | 4.7  | 1.3               | 5.6         | 6.2          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V           | 1.3   | 2.8                | 4.3  | 1.2               | 4.9         | 5.4          | ns   |
| <b>C<sub>L</sub> = 15 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | nA, nB to nY; see <a href="#">Figure 7</a> | [2]   |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                    | -     | 24.5               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V           | 3.4   | 6.9                | 14.8 | 3.1               | 16.5        | 18.2         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V           | 2.8   | 5.0                | 8.9  | 2.5               | 10.5        | 11.6         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V         | 2.0   | 4.1                | 7.0  | 2.0               | 8.3         | 9.2          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V           | 1.7   | 3.5                | 5.3  | 1.5               | 6.4         | 7.1          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V           | 1.6   | 3.2                | 4.9  | 1.4               | 5.7         | 6.3          | ns   |
| <b>C<sub>L</sub> = 30 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | nA, nB to nY; see <a href="#">Figure 7</a> | [2]   |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                    | -     | 34.8               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V           | 4.6   | 9.2                | 20.1 | 4.1               | 22.6        | 24.9         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V           | 3.0   | 6.5                | 11.8 | 2.9               | 14.0        | 15.4         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V         | 2.6   | 5.4                | 9.3  | 2.3               | 11.1        | 12.3         | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V           | 2.4   | 4.6                | 7.1  | 2.1               | 8.5         | 9.4          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V           | 2.3   | 4.3                | 6.5  | 2.1               | 7.6         | 8.4          | ns   |

**Table 8. Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

| Symbol  | Parameter                     | Conditions   | 25 °C |                    |     | −40 °C to +125 °C |                |                 | Unit |
|---|-------------------------------|--|-------|--------------------|-----|-------------------|----------------|-----------------|------|
|   |                               |  | Min   | Typ <sup>[1]</sup> | Max | Min               | Max<br>(85 °C) | Max<br>(125 °C) |      |
| <b>C<sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF</b> |                               |  |       |                    |     |                   |                |                 |      |
| C <sub>PD</sub>                                     | power dissipation capacitance | f <sub>i</sub> = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub> | [3]   |                    |     |                   |                |                 |      |
|   |                               | V <sub>CC</sub> = 0.8 V  | -     | 2.8                | -   | -                 | -              | -               | pF   |
|   |                               | V <sub>CC</sub> = 1.1 V to 1.3 V                                   | -     | 2.9                | -   | -                 | -              | -               | pF   |
|   |                               | V <sub>CC</sub> = 1.4 V to 1.6 V                                   | -     | 3.0                | -   | -                 | -              | -               | pF   |
|   |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                                 | -     | 3.0                | -   | -                 | -              | -               | pF   |
|   |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                   | -     | 3.4                | -   | -                 | -              | -               | pF   |
|   |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                   | -     | 3.9                | -   | -                 | -              | -               | pF   |

[1] All typical values are measured at nominal V<sub>CC</sub>.[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu\text{W}$ ).

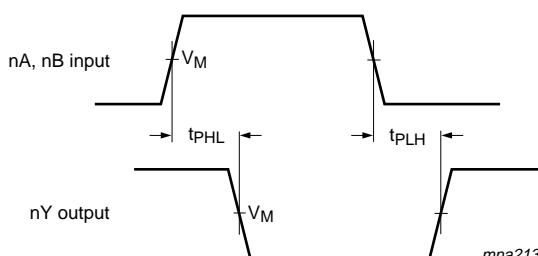
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;f<sub>o</sub> = output frequency in MHz;C<sub>L</sub> = output load capacitance in pF;V<sub>CC</sub> = supply voltage in V;

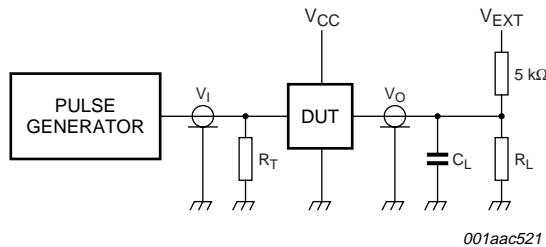
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

## 12. Waveforms

Measurement points are given in [Table 9](#).Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drop that occur with the output load.**Fig 7. The data input (nA or nB) to output (nY) propagation delays****Table 9. Measurement points**

| Supply voltage                    | Output                                  | Input                                   |                                   |   |
|-----------------------------------|---|---|-----------------------------------|---|
| V <sub>CC</sub><br>0.8 V to 3.6 V | V <sub>M</sub><br>0.5 × V <sub>CC</sub> | V <sub>M</sub><br>0.5 × V <sub>CC</sub> | V <sub>I</sub><br>V <sub>CC</sub> | t <sub>r</sub> = t <sub>f</sub><br>≤ 3.0 ns |



Test data is given in [Table 10](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 8. Load circuitry for switching times**

**Table 10. Test data**

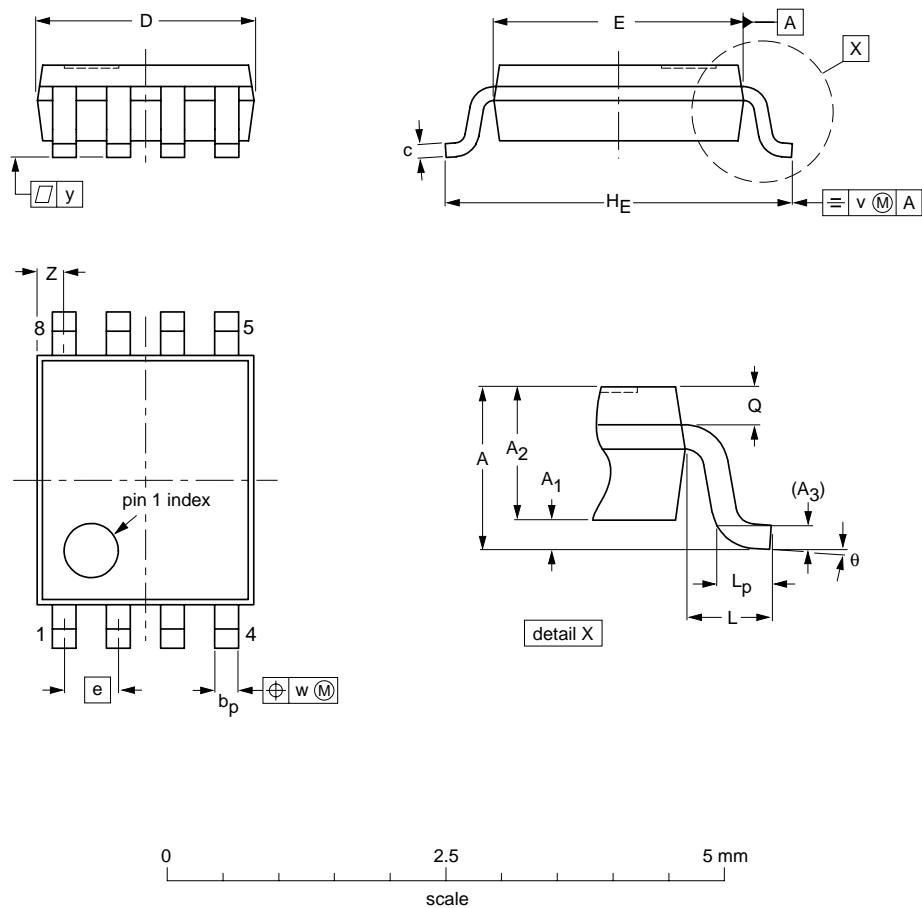
| Supply voltage | Load                         | $V_{EXT}$            |                    |                    |                    |
|----------------|------------------------------|----------------------|--------------------|--------------------|--------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ <sup>[1]</sup> | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ         | open               | GND                | 2 × $V_{CC}$       |

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

## 13. Package outline

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1



### DIMENSIONS (mm are the original dimensions)

| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c            | D <sup>(1)</sup> | E <sup>(2)</sup> | e   | H <sub>E</sub> | L   | L <sub>p</sub> | Q            | v   | w    | y   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|-----|----------------|--------------|-----|------|-----|------------------|----------|
| mm   | 1         | 0.15<br>0.00   | 0.85<br>0.60   | 0.12           | 0.27<br>0.17   | 0.23<br>0.08 | 2.1<br>1.9       | 2.4<br>2.2       | 0.5 | 3.2<br>3.0     | 0.4 | 0.40<br>0.15   | 0.21<br>0.19 | 0.2 | 0.13 | 0.1 | 0.4<br>0.1       | 8°<br>0° |

### Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE<br>VERSION | REFERENCES |        |       | EUROPEAN<br>PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-------|------------------------|------------|
|                    | IEC        | JEDEC  | JEITA |                        |            |
| SOT765-1           |            | MO-187 |       |                        | 02-06-07   |

Fig 9. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body  $1 \times 1.95 \times 0.5$  mm

SOT833-1

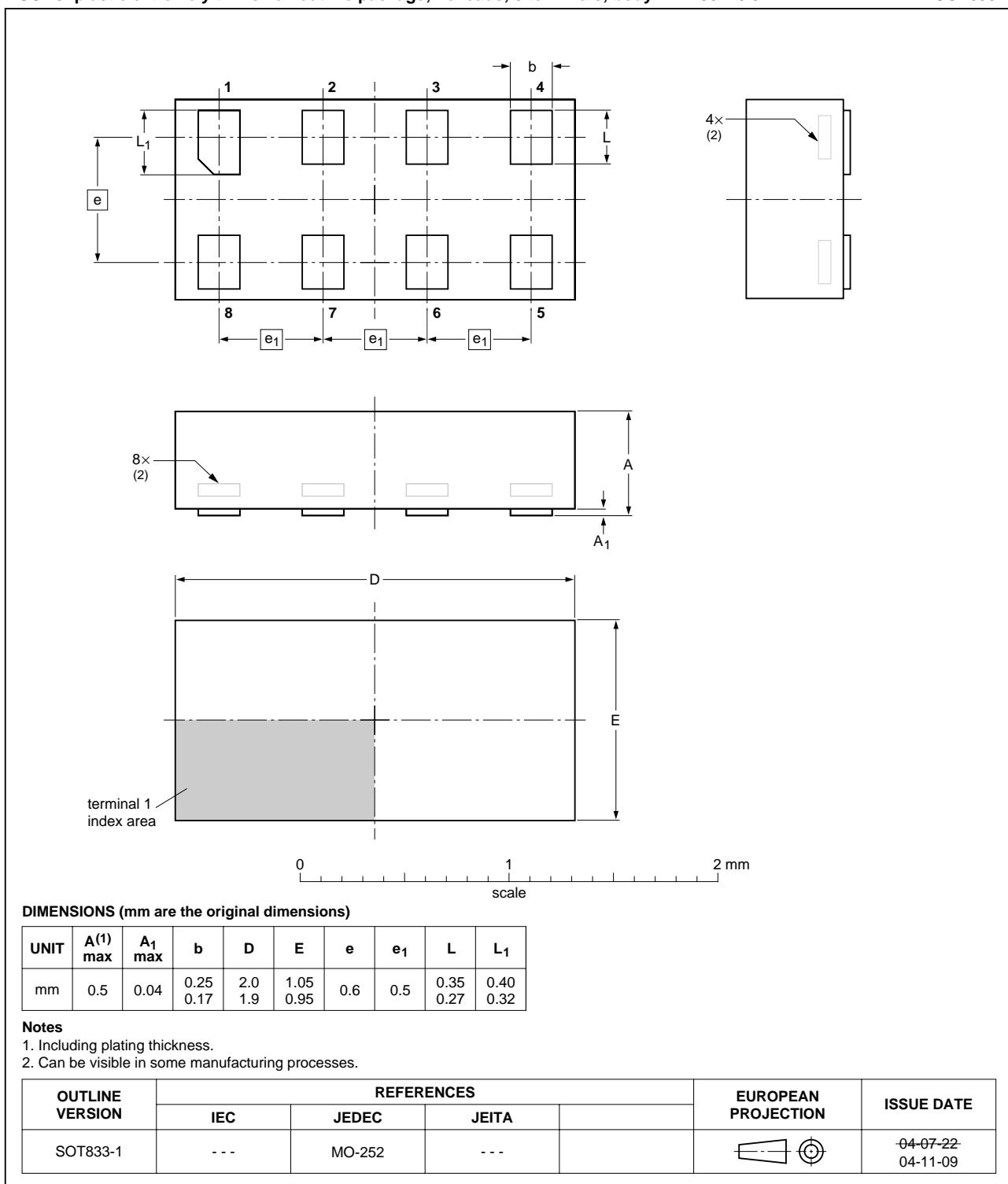


Fig 10. Package outline SOT833-1 (XSON8)

XQFN8: plastic extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-1

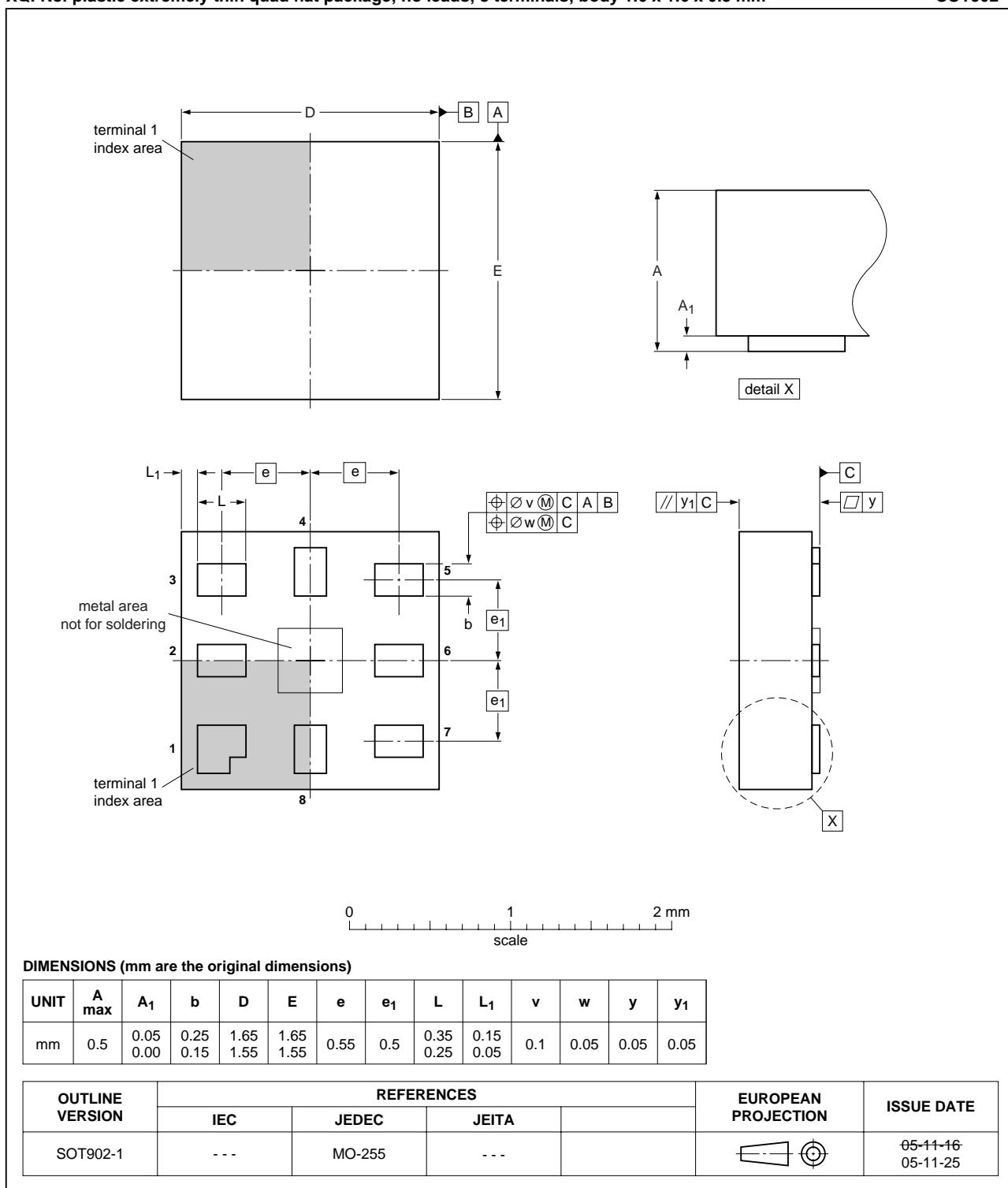


Fig 11. Package outline SOT902-1 (XQFN8)

## 14. Abbreviations

**Table 11. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 15. Revision history

**Table 12. Revision history**

| Document ID | Release date | Data sheet status  | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| 74AUP2G00_1 | 20060825     | Product data sheet | -             | -          |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 25 August 2006

Document identifier: 74AUP2G00\_1